NSN 5961-01-159-0847

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View Online at https://aerobasegroup.com/nsn/5961-01-159-0847 **Inclosure Material:** Metal **Overall Length:** 0.225 inches **Overall Diameter:** 0.356 inches **Internal Configuration:** Junction contact **Mounting Method:** Press fit **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 50.0 collector to emitter reverse voltage, with base short-circuited to emitter and 30.0 collector to emitter voltage/static/base open and 4.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 1.00 amperes source cutoff current **Power Rating Per Characteristic:** 30.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Precious Material And Location:** Lead gold **Precious Material:** Gold **Terminal Type And Quantity:** 3 ribbon Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: